

engineering data service

SYLVANIA

6146A 6159A 6883A

ADVANCE DATA

MECHANICAL DATA

Bulb		T-12
Base	B8-98, B8-86,	Large Wafer Octal 8-Pin
		With Metal Sleeve
	B8-150, B8-159,	Small Wafer Octal 8-Pin
		With Metal Sleeve
Outline		See Drawing
Top Cap		Cl-1 or Cl-38
Basing		7CK
Cathode		Coated Unipotential
Mounting	Position	Any
Bulb Tem		·
(At Ho	ttest Point)	220°C

ELECTRICAL DATA

C007 A

C1504

6146A

HEATER CHARACTERISTICS

	0140A	OBSOA	0159A	
Heater Voltage ± 10%	6.3	12.6	26.5	Volts
Heater Current at				
Specified Voltage	1250	625	300	Ma.
Heater Current Range				
at Specified Voltage	1175-1325	588-663	280-320	Ma.
Heater-Cathode Voltage	(Absolute	Maximum	Values)	
Heater Negative with	Respect to	Cathode	135	Volts
Heater Positive with	Respect to	Cathode	e 135	Volts

MAINTENANCE OF POWFR CAPABILITY

With heater voltage reduced to 5.0 Volts for Type 6146A, 10.0 Volts for Type 6883A and 21.0 Volts for Type 6159A, the power output obtained under the classes of service contained in these defining data will not be reduced by more than ten percent from that obtained at rated heater voltage. Plate input power for the classes of service would be maintained at that obtained using rated heater voltage.

DIRECT INTERELECTRODE CAPACITANCES (Unshielded)

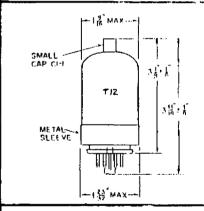
Grid No. 1 to Plate	0.24	μμf Max.
Input	13.5	μμf
Output	8.5	uµf

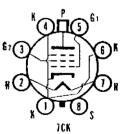
QUICK REFERENCE DATA

Sylvania Types 6146A. 6159A and 6883A are beam power pentodes designed for use at frequencies up to 175 Mc's. In Class "C" Telegraphy Service they can furnish 70 watts of power output under ICAS conditions. 6146A, 6159A and 6883A are designed to provide more stable power output when operating at reduced heater voltage than the prototype versions 6146, 6159 and 6883. An additional feature is a new base (see outline) that

offers greater flexibility

to the design engineer.





SYLVANIA ELECTRONIC TUBES

A Division of Sylvania Electric Products, Inc.

RECEIVING TUBE OPERATIONS

EMPORIUM, PENNSYLVANIA

Prepared and Released By The TECHNICAL PUBLICATIONS SECTION EMPORIUM, PENNSYLVANIA

> August 15, 1961 Page 1 of 5

6146A 6159A 6883A

Page 2

RATINGS (Absolute Maximum Values)

AF Amplifier Service

	P-P		P-P		
	Class AB1		Class AB2		
	ccs	ICAS	ccs	ICAS	
Plate Voltage	600	750	600	750	Volts
Grid No. 2 Voltage	250	250	250	250	Volts
Plate Current (Max. Signal)	125	135	125	135	Volts
Plate Input (Max. Signal)	60	85	62.5	90	Ma.
Plate Dissipation	20	25	20	25	Watts
Grid No. 2 Input (Max. Signal)	3	3	3	3	Watts
Grid No. 1 Circuit Resistance	0.1	0.1	.03	.03	Megohm

RF Amplifier Service - Class "C"

		Telegraphy					
	or or						
	Telej	ohony	F.M. Telephony				
	ccs	ICAS	ccs	ICAS			
Plate Voltage	480	600	600	750	Volts		
Grid No. 2 Voltage	250	250	250	250	Volts		
Grid No. 1 Voltage	-150	-150	-150	-150	Volts		
Plate Current	117	125	140	150	Ma.		
Grid No. 1 Current	3.5	4.0	3.5	4.0	Ma.		
Plate Input	45	67.5	67.5	90	Watts		
Plate Dissipation	13.3	16.7	20	25	Watts		
Grid No. 2 Input	2	2	3	3	Watts		
Grid No. 1 Circuit Resistance	.03	.03	.03	.03	Megohm		

CHARACTERISTICS

Plate Voltage	200	Volts
Grid No. 2 Voltage	200	Volts
Plate Current	100	Ma.
Transconductance	7000	μmhos
Amplification Factor (G1 to G2)	4.5	

CHARACTERISTICS RANGE VALUES FOR EQUIPMENT DESIGN

	Minimum	Maximum
Heater Current		
6146A at 6.3 Volts	1175	1325 Ma.
6883A at 12.6 Volts	588	663 Ma.
6159A at 26.5 Volts	280	320 Ma.

6146A 6159A 6883A

Page 3

CHARACTERISTICS RANGE VALUES FOR EQUIPMENT DESIGN (Cont'	CHARACTERISTICS	RANGE	VALUES	FOR	EOUIPMENT	DESIGN	(Cont 'c
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Grid No. 1 to Plate ⁶	-	0.24	μμf
Input: gl to (k+g3+I.S.+Base Sleeve+g2+h) ⁶ Output: p to (k+g3+I.S.+Base Sleeve+g2+h) ⁶	11.1	15.9	μμf
Output: p to (k+g3+I.S.+Base Sleeve+g2+h)	6.4	10.6	μμf
Plate Current			. ,
(Ef = Rated Value, Eb = 300V, Ec2 = 200V,			
Ec1 = -33V)	46	94	Ma.
Grid No. 2 Current			
(Ef = Rated Value, $Eb = 300V$, $Ec2 = 200V$,			
Ec1 = -33V)	-	5.5	Ma.
Useful Power Output - Self Excited Oscillator	Circuit		
(Ef = Rated Value, Eb = 600V, Ec2 = 180V, R	gl =		
$30,000$ Ohms $\pm 10\%$, Ib = $100-112$ Ma. and I	cl =		
2 to 2.5 Ma at a Frequency of 15 Mc's.)	47	_	Watts

TYPICAL OPERATION

AF Power Amplifier - Class AB1

Plate Current (Zero Signal)

Plate Current (Max. Signal)

Load Resistance (Pl. to Pl.)

Driving Power (Max. Signal)³

Power Output (Max. Signal)

Grid No. 2 Current (Zero Signal)

Grid No. 2 Current (Max. Signal)

Grid No. 1 Current (Max. Signal)

•						
	ccs	ccs	ccs	ICAS	ICAS	
Plate Voltage	400	500	600	600	750	Volts
Grid No. 2 Voltage	190	185	180	200	195	Volts
Grid No. 1 Voltage	-40	-40	-45	-50	-50	Volts
Peak AF Gl to Gl Voltage	80	80	90	100	100	Volts
Plate Current (Zero Signal)	63	57	26	28	23	Ma.
Plate Current (Max. Signal)	228	215	200	229	220	Ma.
Grid No. 2 Current (Zero Signal)	2.5	2.0	1.0	1.0	1.0	Ma.
Grid No. 2 Current (Max. Signal)	25	25	23	27	26	Ma.
Load Resistance (Pl. to Pl.)	4K	5.5K	7K	6K	8K	Ohms
Power Output	55	70	82	95	120	Watts
AF Power Amplifier - Class AB2						
Plate Voltage	400	500	600	600	750	Volts
Grid No. 2 Voltage	175	175	165	190	165	Volts
Grid No. 1 Voltage	-41	-44	-44	-48	-46	Volts
Peak AF G1 to G1 Voltage	95	102	97	109	108	Volts

27

242

0.7

18

1.9

0.3

83

4.6K

33

232

1.1

1.6

3.7K

0.2

62

18

22

207

0.6

1.1

6.8K

0.2

90

17

28

270

1.2

20

2.0

0.3

113

5.OK

22

240

0.3

2.6

0.4

131

7.4K

20

Ma.

Ma.

Ma.

Ma.

Ma.

Ohms

Watts

Watts

SYLVANIA

6146A 6159A 6883A

Page 4

TYPICAL OPERATION (Cont'd)

RF Power Amplifier - Class "C"

Telephony (Up to 60 Mc)

	ccs	ccs	ICAS	
Plate Voltage	400	475	600	Volts
For Grid No. 2 Voltage Use	150	135	150	Volts
Grid No. 2 Dropping Resistor	33K	51K	56K	Ohms
For Grid No. 1 Voltages ⁵	-87	-77	-87	Volts
Use Grid No. 1 Resistor	27K	27K	27K	Ohms
Peak RF Grid No. 1 Voltage	107	95	107	Volts
Grid No. 1 Current	3.4	2.8	3.4	Ma.
Plate Current	112	94	112	Ma.
Grid No. 2 Current	7.8	6.4	7.8	Ma.
Driving Power (Approx.)	0.4	0.3	0.4	Watts
Power Output (Approx.)	32	34	52	Watts

RF Power Amplifier - Class "C"

Telegraphy - F.M. Telephony

		Up	to		Up	to	
		60	Mc		175	5 Mc	
	ccs	ccs	ICAS	ICAS	ccs	ICAS	
Plate Voltage	500	600	600	750	320	400	Volts
For Grid No. 2 Voltage of	170	150	180	160	180	190	Volts
Use Grid No. 2 Dropping							
Resistor	36K	51K	43K	56K	13K	20K	Ohms
For Grid No. 1 Voltage of 5	-66	-58	-71	-62	-51	-54	Volts
Use Grid No. 1 Resistor or	27K	20K	24K	20K	27K	24K	Ohms
Use Cathode Resistor	470	470	430	470	330	330	Ohms
Peak RF Grid No. 1 Voltage	84	73	91	79	64	68	Volts
Grid No. 1 Current	2.5	2.8	2.8	3.1	2	2.2	Ma.
Plate Current	135	112	150	120	140	150	Ma.
Grid No. 2 Current	9	9	10	11	10	10.4	Ma.
Driving Power (Approx.)	0.2	0.2	0.3	0.2	3.0	3.0	Watts
Power Output	48	52	66	70	25	35	Watts

NOTES:

- 1. Carrier conditions per tube with a maximum modulation factor of 1.0.
- 2. Preferably obtained from a separate source or from the plate-voltage supply with a voltage divider.

6146A 6159A 6883A

Page 5

NOTES: (Cont'd).

- 3. The driver stage should be capable of supplying the specified driving power at low distortion to the No. 1 grids of the AB2 stage. To minimize distortion, the effective resistance per Grid No. 1 Circuit should be held to a low value. For this purpose use of transformer coupling is recommended. In no case, however, should the total DC grid circuit resistance exceed 30,000 ohms when the tube is operated at maximum ratings. For operation at less than maximum ratings, the DC grid circuit resistance may be as high as 100,000 ohms.
- 4. Obtained preferably from a separate source modulated with the plate supply, or from the modulated plate supply through a series resistor.
- 5. Grid No. 1 voltage obtained from Grid No. 1 resistor or from a combination of Grid No. 1 resistor with the fixed supply or cathode resistor.
- 6. Unshielded bulb.